74LVC1G384

Bilateral switch

Rev. 7 — 7 December 2016

Product data sheet

1. General description

The 74LVC1G384 provides one single pole, single throw analog switch function. It has two input/output terminals (Y and Z) and an active LOW enable input pin (\overline{E}) . When pin \overline{E} is HIGH, the analog switch is turned off.

Schmitt trigger action at the enable input makes the circuit tolerant of slower input rise and fall times across the entire V_{CC} range from 1.65 V to 5.5 V.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- Very low ON resistance:
 - 7.5 Ω (typical) at $V_{CC} = 2.7 \text{ V}$
 - 6.5 Ω (typical) at $V_{CC} = 3.3 \text{ V}$
 - 6 Ω (typical) at $V_{CC} = 5 \text{ V}$
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Switch current capability of 32 mA
- High noise immunity
- CMOS low power consumption
- TTL interface compatibility at 3.3 V
- Latch-up performance meets requirements of JESD 78 Class I
- Enable input accepts voltages up to 5.5 V
- Inputs accept voltages up to 5 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74LVC1G384GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
74LVC1G384GV	−40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753
74LVC1G384GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886



 Table 1.
 Ordering information ...continued

Type number	Package							
	Temperature range	Name	Description	Version				
74LVC1G384GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm	SOT891				
74LVC1G384GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115				
74LVC1G384GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202				
74LVC1G384GX	-40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8 \times 0.8 \times 0.35$ mm	SOT1226				

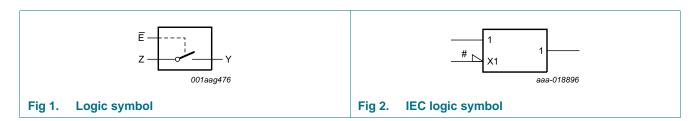
4. Marking

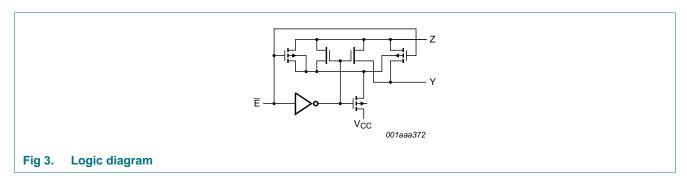
Table 2. Marking

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Type number	Marking code ^[1]
74LVC1G384GW	YL
74LVC1G384GV	YL
74LVC1G384GM	YL
74LVC1G384GF	YL
74LVC1G384GN	YL
74LVC1G384GS	YL
74LVC1G384GX	YL

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

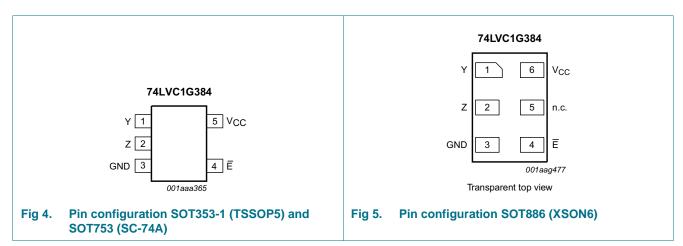
5. Functional diagram





6. Pinning information

6.1 Pinning





6.2 Pin description

Table 3. Pin description

Symbol	Pin		Description	
	TSSOP5 and SC-74	XSON6	X2SON5	
Υ	1	1	3	independent input or output
Z	2	2	5	independent output or input
GND	3	3	2	ground (0 V)
Ē	4	4	4	enable input (active LOW)
n.c.	-	5	-	not connected
V _{CC}	5	6	1	supply voltage

7. Functional description

Table 4. Function table[1]

Input E	Switch
L	ON-state
Н	OFF-state

^[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+6.5	V
VI	input voltage		[1]	-0.5	+6.5	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$		-50	-	mA
I _{SK}	switch clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$		-	±50	mA
V _{SW}	switch voltage	enable and disable mode	[2]	-0.5	V _{CC} + 0.5	V
I _{SW}	switch current	$V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V}$		-	±50	mA
I _{CC}	supply current			-	100	mA
I _{GND}	ground current			-100	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}$ C to +125 $^{\circ}$ C	[3]	-	250	mW

^[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CC}	supply voltage			1.65	-	5.5	V
VI	input voltage			0	-	5.5	V
V _{SW}	switch voltage		<u>[1]</u>	0	-	V _{CC}	V
T _{amb}	ambient temperature			-40	-	+125	°C
Δt/ΔV	input transition rise and	$V_{CC} = 1.65 \text{ V to } 2.7 \text{ V}$		-	-	20	ns/V
	fall rate	$V_{CC} = 2.7 \text{ V to } 5.5 \text{ V}$		-	-	10	ns/V

^[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Y. In this case, there is no limit for the voltage drop across the switch.

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^[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

^[3] For TSSOP5 and SC-74A packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K. For XSON6 and X2SON5 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

10. Static characteristics

Table 7. Static characteristics

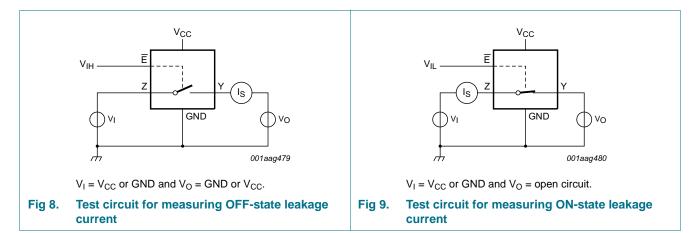
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		-40 °	°C to +8	5 ℃	-40 °C to +125 °C		
				Min	Typ[1]	Max	Min	Max	
V _{IH}	HIGH-level	V _{CC} = 1.65 V to 1.95 V		0.65V _{CC}	-	-	0.65 V _{CC}	-	V
	input voltage	V _{CC} = 2.3 V to 2.7 V		1.7	-	-	1.7	-	V
		V _{CC} = 2.7 V to 3.6 V		2.0	-	-	2.0	-	V
		V _{CC} = 4.5 V to 5.5 V		0.7V _{CC}	-	-	0.7V _{CC}	-	V
V_{IL}	LOW-level	V _{CC} = 1.65 V to 1.95 V		-	-	0.35V _{CC}	-	0.35V _{CC}	V
	input voltage	V _{CC} = 2.3 V to 2.7 V		-	-	0.7	-	0.7	V
		V _{CC} = 2.7 V to 3.6 V		-	-	0.8	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V		-	-	0.3V _{CC}	-	0.3V _{CC}	V
l _l	input leakage current	pin \overline{E} ; V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	[2]	-	±0.1	±1	-	±1	μΑ
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 5.5 V; see <u>Figure 8</u>	[2]	-	±0.1	±0.2	-	±0.5	μΑ
I _{S(ON)}	ON-state leakage current	V _{CC} = 5.5 V; see <u>Figure 9</u>	[2]	-	±0.1	±1	-	±2	μΑ
I _{CC}	supply current	V_I = 5.5 V or GND; V_{SW} = GND or V_{CC} ; V_{CC} = 1.65 V to 5.5 V	[2]	-	0.1	4	-	4	μΑ
ΔI_{CC}	additional supply current	pin \overline{E} ; $V_I = V_{CC} - 0.6 \text{ V}$; $V_{SW} = \text{GND or } V_{CC}$; $V_{CC} = 5.5 \text{ V}$	[2]	-	5	500	-	500	μΑ
Cı	input capacitance			-	2.0	-	-	-	pF
C _{S(OFF)}	OFF-state capacitance			-	5.0	-	-	-	pF
C _{S(ON)}	ON-state capacitance			-	9.5	-	-	-	pF

^[1] All typical values are measured at T_{amb} = 25 °C.

^[2] These typical values are measured at V_{CC} = 3.3 V.

10.1 Test circuits



10.2 ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground 0 V); for graphs see Figure 11 to Figure 16.

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	Unit	
			Min	Typ[1]	Max	Min	Max	
R _{ON(peak)}	ON resistance (peak)	V _I = GND to V _{CC} ; see <u>Figure 10</u>						
	I _{SW} = 4 mA; V _{CC} = 1.65 V to 1.95 V	-	34.0	130	-	195	Ω	
	$I_{SW} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	12.0	30	-	45	Ω	
		I _{SW} = 12 mA; V _{CC} = 2.7 V	-	10.4	25	-	38	Ω
		I _{SW} = 24 mA; V _{CC} = 3 V to 3.6 V	-	7.8	20	-	30	Ω
		I _{SW} = 32 mA; V _{CC} = 4.5 V to 5.5 V	-	6.2	15	-	23	Ω
R _{ON(rail)} ON resistance (rail)	ON resistance (rail)	V _I = GND; see <u>Figure 10</u>						
	I _{SW} = 4 mA; V _{CC} = 1.65 V to 1.95 V	-	8.2	18	-	27	Ω	
		I_{SW} = 8 mA; V_{CC} = 2.3 V to 2.7 V	-	7.1	16	-	24	Ω
		I _{SW} = 12 mA; V _{CC} = 2.7 V	-	6.9	14	-	21	Ω
		I _{SW} = 24 mA; V _{CC} = 3 V to 3.6 V	-	6.5	12	-	18	Ω
		I _{SW} = 32 mA; V _{CC} = 4.5 V to 5.5 V	-	5.8	10	-	15	Ω
		V _I = V _{CC} ; see <u>Figure 10</u>				-		
		I _{SW} = 4 mA; V _{CC} = 1.65 V to 1.95 V	-	10.4	30	-	45	Ω
		$I_{SW} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	7.6	20	-	30	Ω
		I _{SW} = 12 mA; V _{CC} = 2.7 V	-	7.0	18	-	27	Ω
		I _{SW} = 24 mA; V _{CC} = 3 V to 3.6 V	-	6.1	15	-	23	Ω
		$I_{SW} = 32 \text{ mA}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	4.9	10	-	15	Ω

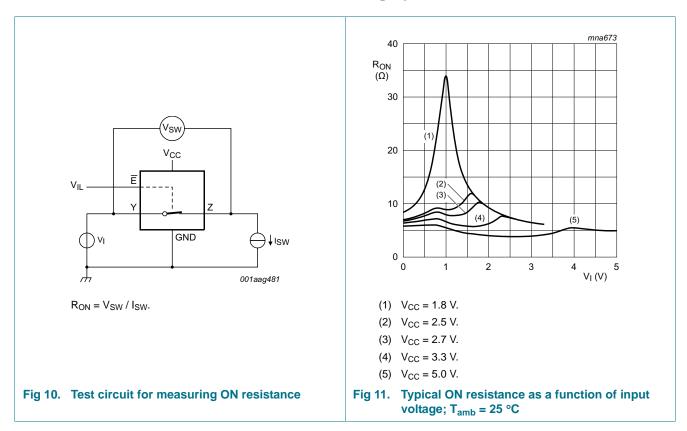
Table 8. ON resistance ... continued

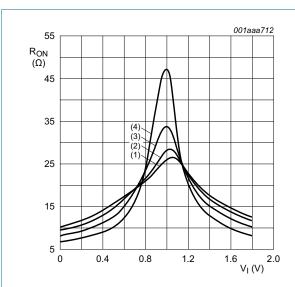
At recommended operating conditions; voltages are referenced to GND (ground 0 V); for graphs see Figure 11 to Figure 16.

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
R _{ON(flat)}	ON resistance	$V_I = GND \text{ to } V_{CC}$ [2]						
(flatness)	$I_{SW} = 4 \text{ mA};$ $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	26.0	-	-	-	Ω	
		I_{SW} = 8 mA; V_{CC} = 2.3 V to 2.7 V	-	5.0	-	-	-	Ω
		I_{SW} = 12 mA; V_{CC} = 2.7 V	-	3.5	-	-	-	Ω
		I_{SW} = 24 mA; V_{CC} = 3 V to 3.6 V	-	2.0	-	-	-	Ω
		I_{SW} = 32 mA; V_{CC} = 4.5 V to 5.5 V	-	1.5	-	-	-	Ω

- [1] Typical values are measured at T_{amb} = 25 °C and nominal V_{CC} .
- [2] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

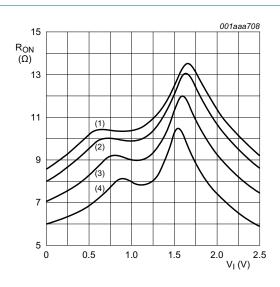
10.3 ON resistance test circuit and graphs





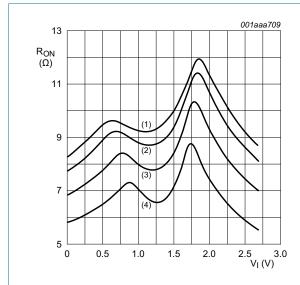
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 12. ON resistance as a function of input voltage; $V_{CC} = 1.8 \text{ V}$



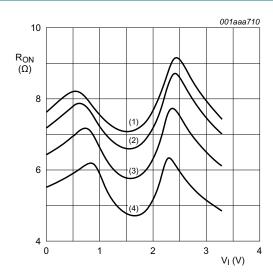
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 13. ON resistance as a function of input voltage; $V_{CC} = 2.5 \text{ V}$



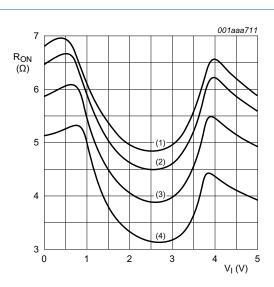
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 14. ON resistance as a function of input voltage; $V_{CC} = 2.7 \text{ V}$



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 15. ON resistance as a function of input voltage; $V_{CC} = 3.3 \text{ V}$



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \,^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 16. ON resistance as a function of input voltage; $V_{CC} = 5.0 \text{ V}$

11. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 19.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	Y to Z or Z to Y; see Figure 17 [2][3]						
		V _{CC} = 1.65 V to 1.95 V	-	0.8	2.0	-	3.0	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.4	1.2	-	2.0	ns
		V _{CC} = 2.7 V	-	0.4	1.0	-	1.5	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.3	0.8	-	1.5	ns
		V _{CC} = 4.5 V to 5.5 V	-	0.2	0.6	-	1.0	ns
t _{en}	enable time	E to Y or Z; see Figure 18 [4]						
		V _{CC} = 1.65 V to 1.95 V	1.0	10.0	12.0	1.0	15.5	ns
		V _{CC} = 2.3 V to 2.7 V	1.0	5.7	6.5	1.0	8.5	ns
		V _{CC} = 2.7 V	1.0	5.4	6.0	1.0	8.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	4.8	5.0	1.0	6.5	ns
		V _{CC} = 4.5 V to 5.5 V	1.0	3.3	4.2	1.0	5.5	ns

Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 19.

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
t _{dis}	disable time	E to Y or Z; see Figure 18						
		V _{CC} = 1.65 V to 1.95 V	1.0	7.4	10.0	1.0	13.0	ns
		V _{CC} = 2.3 V to 2.7 V	1.0	4.1	6.9	1.0	9.0	ns
		V _{CC} = 2.7 V	1.0	4.9	7.5	1.0	9.5	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	5.4	6.5	1.0	8.5	ns
		V _{CC} = 4.5 V to 5.5 V	1.0	3.6	5.0	1.0	6.5	ns
C _{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; f_i = 10 \text{ MHz};$ [6] $V_I = \text{GND to } V_{CC}$						
		V _{CC} = 2.5 V	-	13.7	-	-	-	pF
		V _{CC} = 3.3 V	-	15.2	-	-	-	pF
		V _{CC} = 5.0 V	-	18.3	-	-	-	pF

- [1] Typical values are measured at T_{amb} = 25 °C and nominal V_{CC} .
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [3] propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified capacitance when driven by an ideal voltage source (zero output impedance).
- [4] t_{en} is the same as t_{PZH} and t_{PZL} .
- [5] t_{dis} is the same as t_{PLZ} and t_{PHZ} .
- [6] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma \{ (C_L + C_{S(ON)}) \times V_{CC}^2 \times f_o \} \text{ where: }$

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

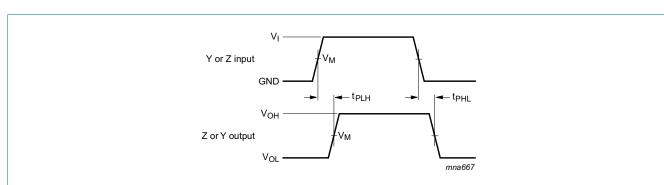
C_{S(ON)} = maximum ON-state switch capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma \{(C_L + C_{S(ON)}) \times V_{CC}^2 \times f_o\} = \text{sum of the outputs.}$

11.1 Waveforms and test circuit



Measurement points are given in Table 10.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 17. Input (Y or Z) to output (Z or Y) propagation delays

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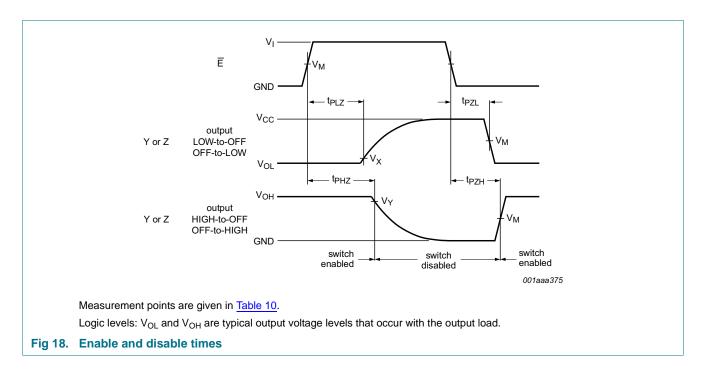
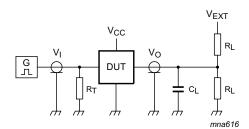


Table 10. Measurement points

Supply voltage	Input	Output		
V _{CC}	V _M	V _M	V _X	V _Y
1.65 V to 1.95 V	0.5V _{CC}	0.5V _{CC}	V _{OL} + 0.15 V	V _{OH} – 0.15 V
2.3 V to 2.7 V	0.5V _{CC}	0.5V _{CC}	V _{OL} + 0.15 V	V _{OH} – 0.15 V
2.7 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} – 0.3 V
3.0 V to 3.6 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} – 0.3 V
4.5 V to 5.5 V	0.5V _{CC}	0.5V _{CC}	V _{OL} + 0.3 V	V _{OH} – 0.3 V



Test data is given in Table 11.

Definitions for test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

 V_{EXT} = External voltage for measuring switching times.

Fig 19. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Input	Input		Load		V _{EXT}			
V _{CC}	VI	t _r , t _f	CL	R _L	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}		
1.65 V to 1.95 V	V _{CC}	≤ 2.0 ns	30 pF	1 kΩ	open	GND	2V _{CC}		
2.3 V to 2.7 V	V _{CC}	≤ 2.0 ns	30 pF	500 Ω	open	GND	2V _{CC}		
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	GND	6 V		
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	GND	6 V		
4.5 V to 5.5 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open	GND	2V _{CC}		

11.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

At recommended operating conditions; typical values measured at $T_{amb} = 25$ °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic distortion	$R_L = 10 \text{ k}\Omega$; $C_L = 50 \text{ pF}$; $f_i = 1 \text{ kHz}$; see Figure 20				
		V _{CC} = 1.65 V	-	0.032	-	%
		V _{CC} = 2.3 V	-	0.008	-	%
		V _{CC} = 3.0 V	-	0.006	-	%
		V _{CC} = 4.5 V	-	0.001	-	%
		$R_L = 10 \text{ k}\Omega$; $C_L = 50 \text{ pF}$; $f_i = 10 \text{ kHz}$; see Figure 20				
		V _{CC} = 1.65 V	-	0.068	-	%
		V _{CC} = 2.3 V	-	0.009	-	%
		V _{CC} = 3.0 V	-	0.008	-	%
		V _{CC} = 4.5 V	-	0.006	-	%

Table 12.Additional dynamic characteristics ...continuedAt recommended operating conditions; typical values measured at $T_{amb} = 25 \, ^{\circ}$ C.

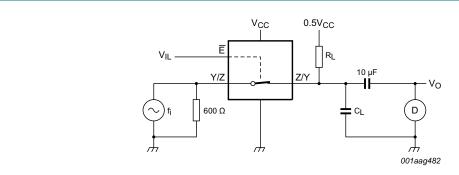
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f _(-3dB)	-3 dB frequency response	$R_L = 600 \Omega$; $C_L = 50 pF$; see Figure 21				
		V _{CC} = 1.65 V	-	135	-	MHz
		V _{CC} = 2.3 V	-	145	-	MHz
		V _{CC} = 3.0 V	-	150	-	MHz
		V _{CC} = 4.5 V	-	155	-	MHz
		$R_L = 50 \Omega$; $C_L = 5 pF$; see Figure 21				
		V _{CC} = 1.65 V	-	> 500	-	MHz
		V _{CC} = 2.3 V	-	> 500	-	MHz
		V _{CC} = 3.0 V	-	> 500	-	MHz
		V _{CC} = 4.5 V	-	> 500	-	MHz
		$R_L = 50 \Omega$; $C_L = 10 pF$; see Figure 21				
		V _{CC} = 1.65 V	-	200	-	MHz
		V _{CC} = 2.3 V	-	350	-	MHz
		V _{CC} = 3.0 V	-	410	-	MHz
		V _{CC} = 4.5 V	-	440	-	MHz
α_{iso}	isolation (OFF-state)	$R_L = 600 \Omega$; $C_L = 50 pF$; $f_i = 1 MHz$; see Figure 22				
		V _{CC} = 1.65 V	-	-46	-	dB
		V _{CC} = 2.3 V	-	-46	-	dB
		V _{CC} = 3.0 V	-	-46	-	dB
		V _{CC} = 4.5 V	-	-46	-	dB
		$R_L = 50 \Omega$; $C_L = 5 pF$; $f_i = 1 MHz$; see Figure 22				
		V _{CC} = 1.65 V	-	-37	-	dB
		V _{CC} = 2.3 V	-	-37	-	dB
		V _{CC} = 3.0 V	-	-37	-	dB
		V _{CC} = 4.5 V	-	-37	-	dB
V _{ct}	crosstalk voltage	between digital input and switch;				
		$R_L = 600 \Omega$; $C_L = 50 pF$; $f_i = 1 MHz$; $t_r = t_f = 2 ns$; see Figure 23				
		V _{CC} = 1.65 V	-	69	-	mV
		V _{CC} = 2.3 V	-	87	-	mV
		V _{CC} = 3.0 V	-	156	-	mV
		V _{CC} = 4.5 V	-	302	-	mV

Table 12. Additional dynamic characteristics ... continued

At recommended operating conditions; typical values measured at T_{amb} = 25 °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Q _{inj}	charge injection	C_L = 0.1 nF; V_{gen} = 0 V; R_{gen} = 0 Ω ; f_i = 1 MHz; R_L = 1 M Ω ; see Section 11				
		V _{CC} = 1.8 V	-	3.3	-	рС
		V _{CC} = 2.5 V	-	4.1	-	рС
		V _{CC} = 3.3 V	-	5.0	-	pC
		V _{CC} = 4.5 V	-	6.4	-	pC
		V _{CC} = 5.5 V	-	7.5	-	рС

11.3 Test circuits



Test conditions:

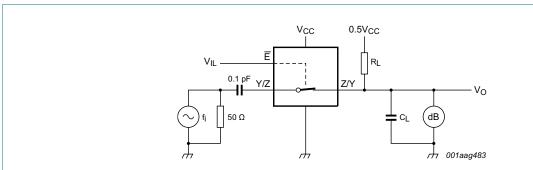
 $V_{CC} = 1.65 \text{ V: } V_I = 1.4 \text{ V (p-p)}.$

 $V_{CC} = 2.3 \text{ V: } V_I = 2 \text{ V (p-p)}.$

 $V_{CC} = 3 \text{ V: } V_I = 2.5 \text{ V (p-p)}.$

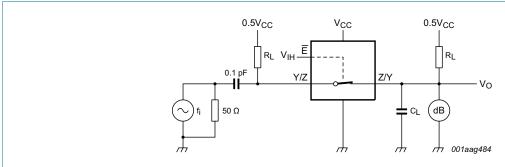
 $V_{CC} = 4.5 \text{ V: } V_I = 4 \text{ V (p-p)}.$

Fig 20. Test circuit for measuring total harmonic distortion



Adjust f_i voltage to obtain 0 dBm level at output. Increase f_i frequency until dB meter reads -3 dB.

Fig 21. Test circuit for measuring the frequency response when switch is in ON-state



Adjust fi voltage to obtain 0 dBm level at input.

Fig 22. Test circuit for measuring isolation (OFF-state)

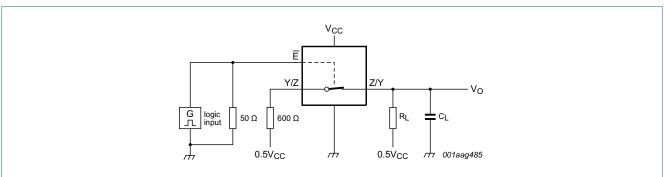
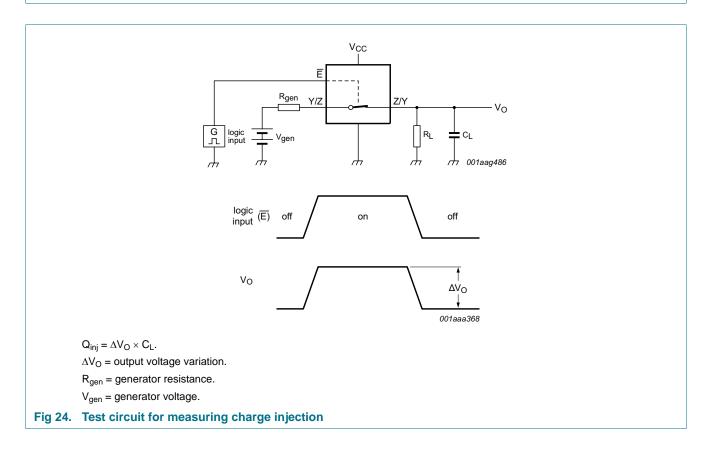


Fig 23. Test circuit for measuring crosstalk between digital inputs and switch

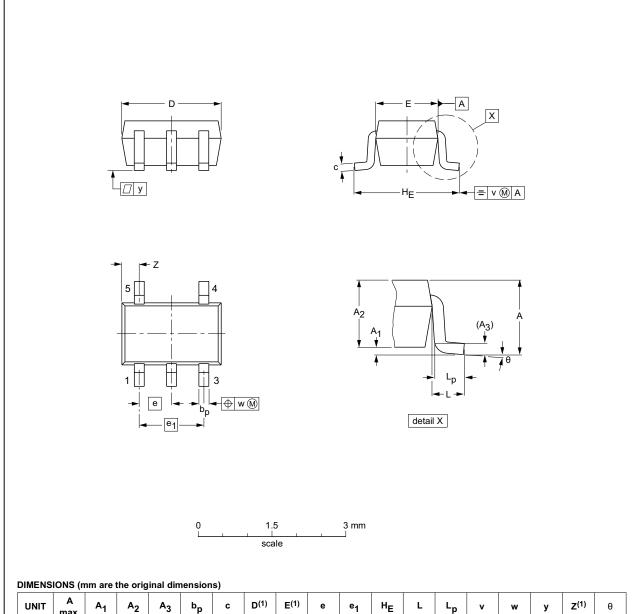


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12. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	С	D ⁽¹⁾	E(1)	е	e ₁	HE	L	Lp	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.1 0	1.0 0.8	0.15	0.30 0.15	0.25 0.08	2.25 1.85	1.35 1.15	0.65	1.3	2.25 2.0	0.425	0.46 0.21	0.3	0.1	0.1	0.60 0.15	7° 0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT353-1		MO-203	SC-88A		00-09-01 03-02-19

Fig 25. Package outline SOT353-1 (TSSOP5)

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Plastic surface-mounted package; 5 leads

SOT753

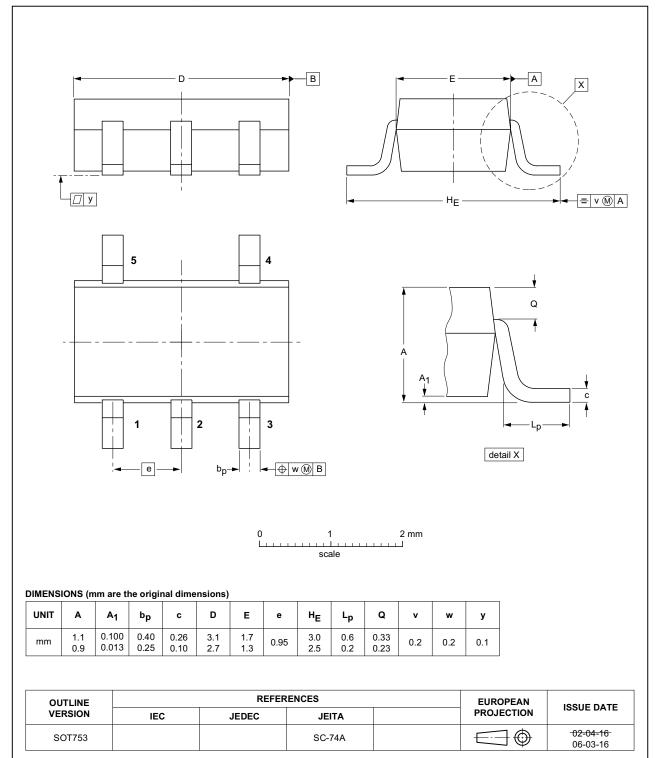


Fig 26. Package outline SOT753 (SC-74A)

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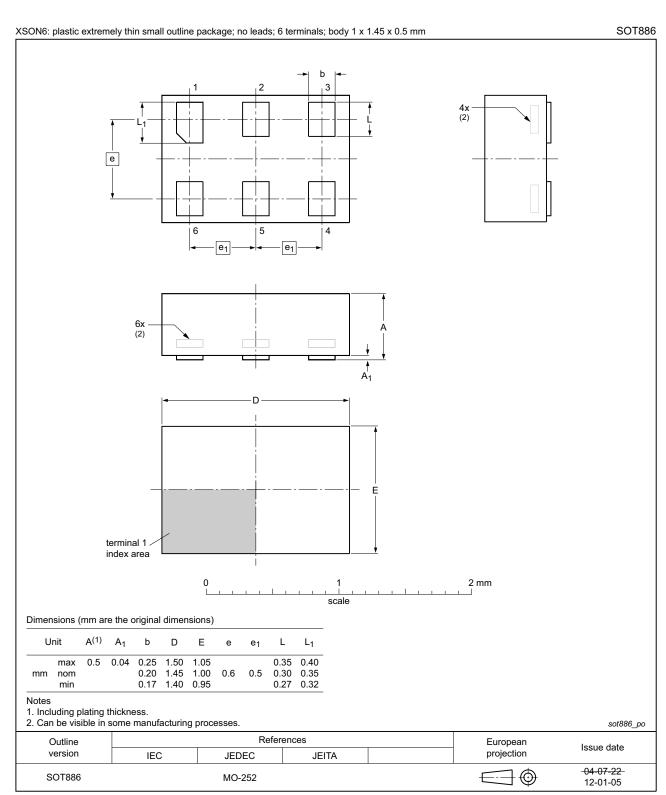


Fig 27. Package outline SOT886 (XSON6)

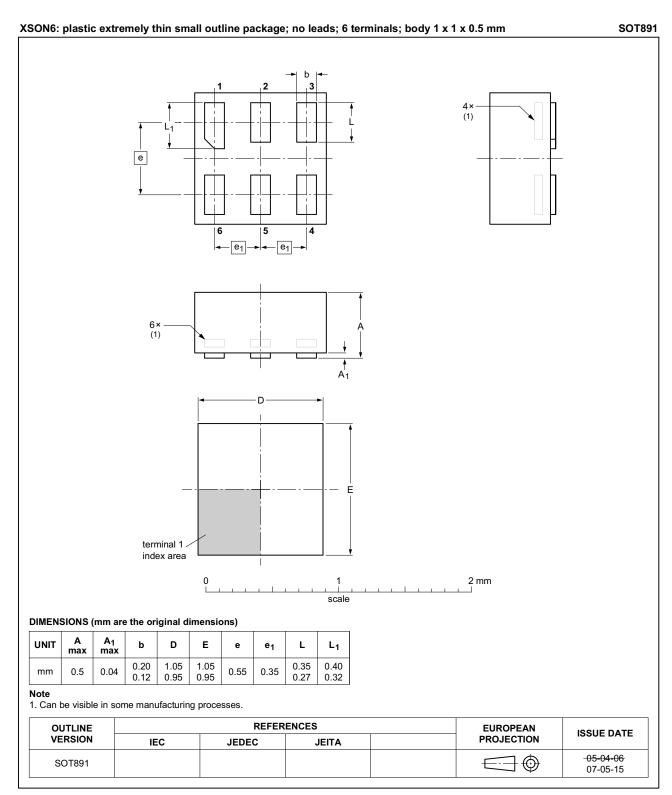


Fig 28. Package outline SOT891 (XSON6)

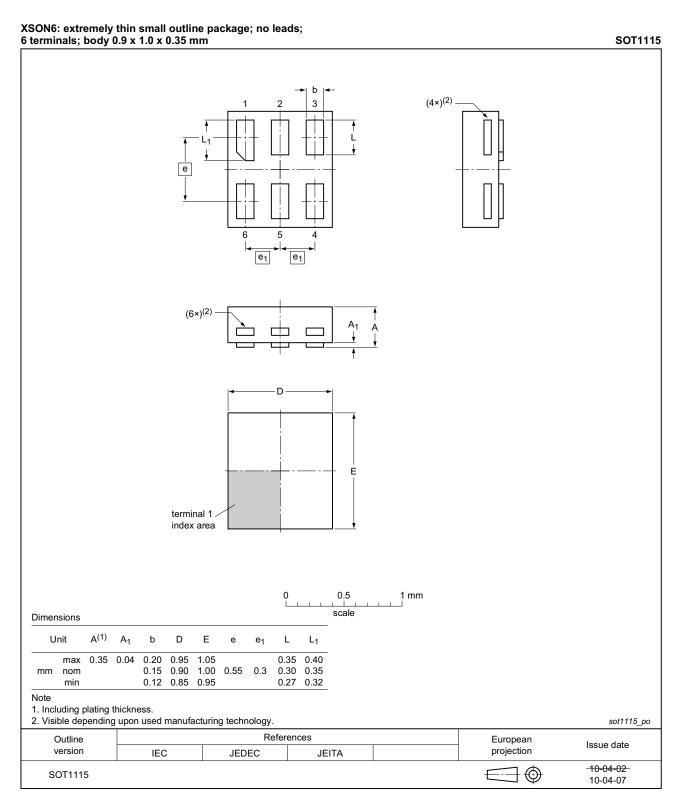


Fig 29. Package outline SOT1115 (XSON6)

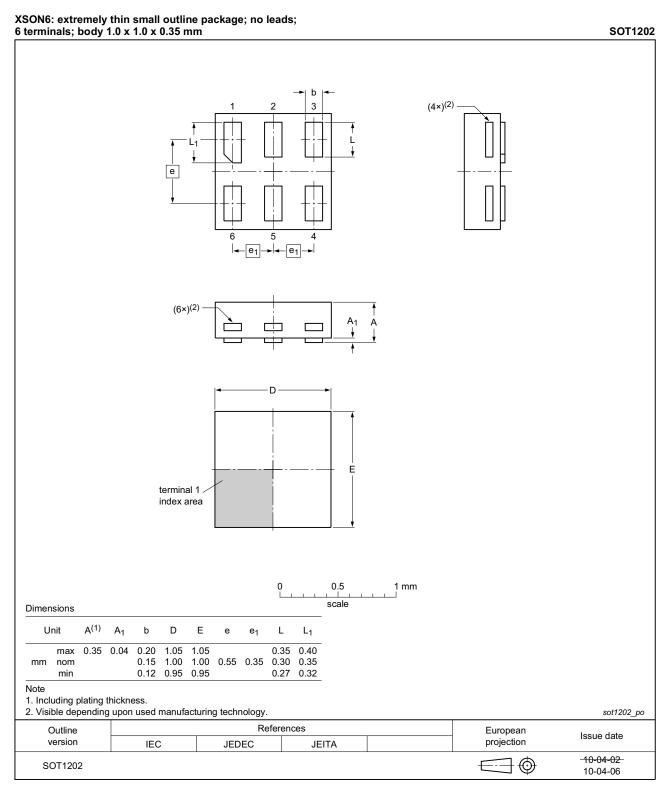


Fig 30. Package outline SOT1202 (XSON6)

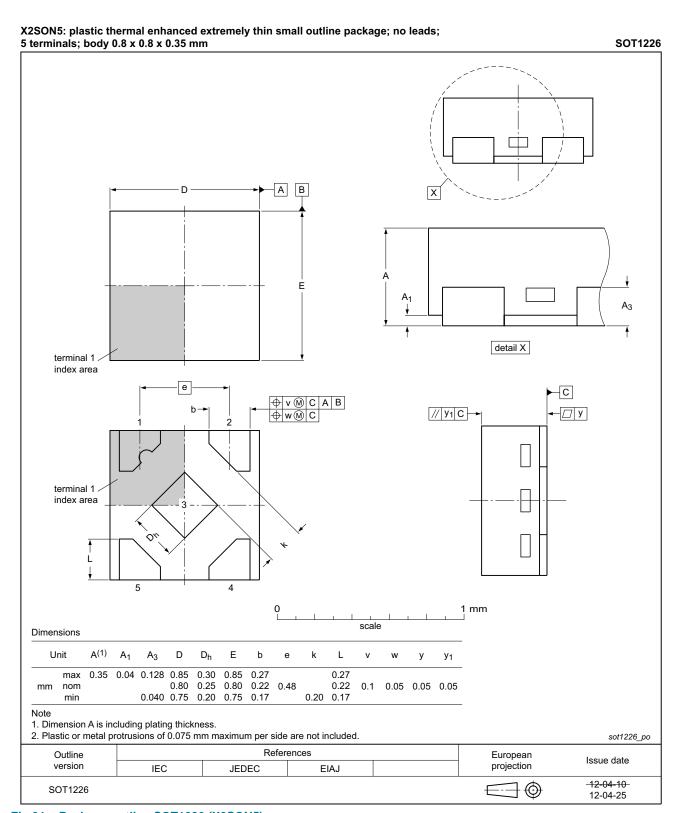


Fig 31. Package outline SOT1226 (X2SON5)

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13. Abbreviations

Table 13. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G384 v.7 20161207		Product data sheet	-	74LVC1G384 v.6
Modifications:	• <u>Table 7</u> : The	maximum limits for leakag	ge current and supply cu	rrent have changed.
74LVC1G384 v.6	20150903	Product data sheet	-	74LVC1G384 v.5
Modifications:	Added type	number 74LVC1G384GX (SOT1226)	
74LVC1G384 v.5 20150115		Product data sheet	-	74LVC1G384 v.4
Modifications:	• SOT886 (XS	ON6) package outline dra	wing modified.	
74LVC1G384 v.4	20111206	Product data sheet	-	74LVC1G384 v.3
Modifications:	 Legal pages 	updated.		
74LVC1G384 v.3 20101103 Pr		Product data sheet	-	74LVC1G384 v.2
74LVC1G384 v.2	20070829	Product data sheet	-	74LVC1G384 v.1
74LVC1G384 v.1	20040226	Product data	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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